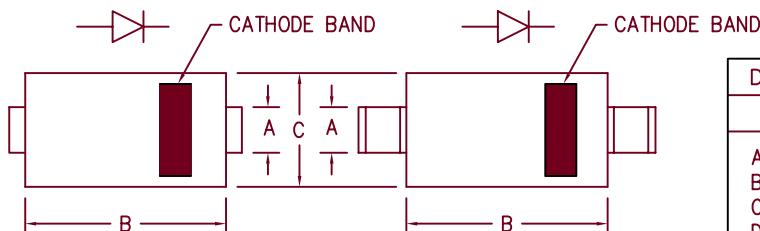


8 Amp Schottky Rectifier

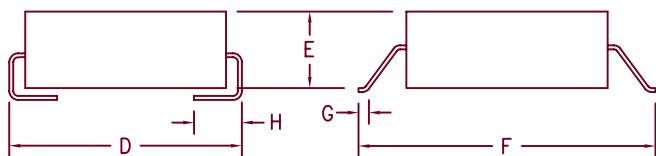
HSM825 — HSM845



D0214AB

D0215AB

Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	.117	.123	2.97	3.12	
B	.260	.280	6.60	7.11	
C	.220	.245	5.59	6.22	
D	.307	.322	7.80	8.18	
E	.075	.095	1.91	2.41	
F	.380	.400	9.65	10.16	
G	.025	.040	.640	1.02	
H	.030	.060	.760	1.52	



Microsemi Catalog Number	Industry Part Number	Working Reverse Voltage	Peak Reverse Voltage	Repetitive Peak Reverse Voltage
HSM825*	SK82L	25V	25V	
HSM830*	SL83L	30V	30V	
HSM835*	SK835L	35V	35V	
HSM840*	SK84L	40V	40V	
HSM845*	SK845L	45V	45V	

*Add Suffix J For J Lead or G For Gull Wing Lead Configuration

- Schottky Barrier Rectifier
- Guard Ring Protection
- 175°C Junction Temperature
- High Current Capability
- V_{RRM} 25 to 45 Volts
- Surface mount package

Electrical Characteristics

Average forward current	$I_F(AV)$ 8.0 Amps	Square wave
Maximum surge current	$I_F(AV)$ 350 Amps	8.3ms, half sine, $T_J = 175^\circ\text{C}$
Max peak forward voltage	V_{FM} .47 Volts	$ I_{FM} = 8.0\text{A}; T_J = 150^\circ\text{C}$ *
Max peak forward voltage	V_{FM} .62 Volts	$ I_{FM} = 8.0\text{A}; T_J = 25^\circ\text{C}$ *
Max peak reverse current	I_{RM} 250 μA	$V_{RRM}, T_J = 25^\circ\text{C}$
Typical junction capacitance	C_J 660 pF	$V_R = 5.0\text{V}, T_J = 25^\circ\text{C}$

* Pulse test: Pulse width 300 μsec , Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temperature range	T_{STG}	-55°C to 175°C
Operating junction temp range	T_J	-55°C to 175°C
Maximum thermal resistance	$R_{\theta JL}$	20°C/W Junction to lead
Weight		.008 ounces (.22 grams) typical

 **Microsemi**

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05-15-07 Rev. 3

HSM825 – HSM845

Figure 1
Typical Forward Characteristic

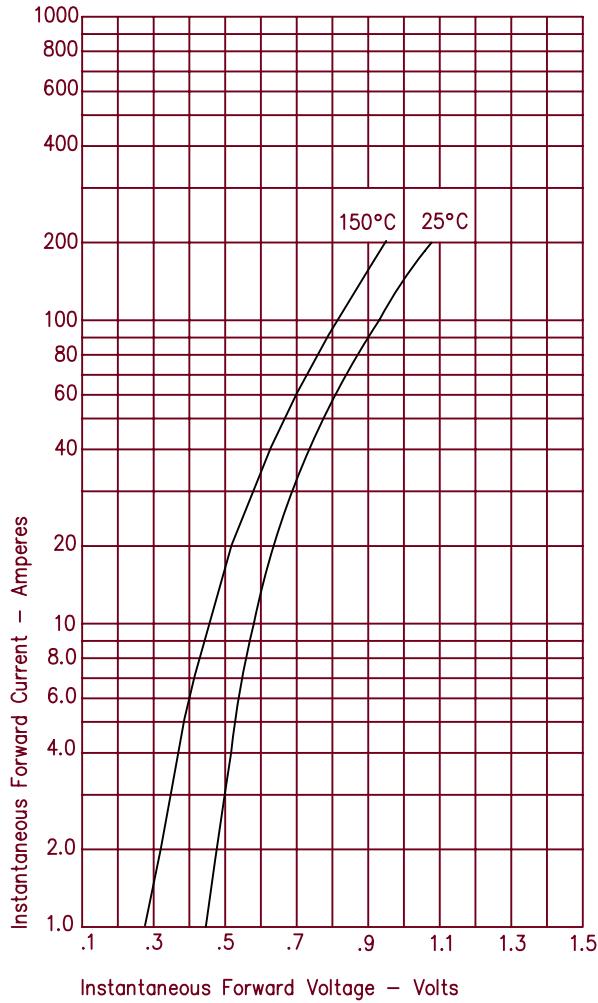


Figure 3
Typical Junction Capacitance

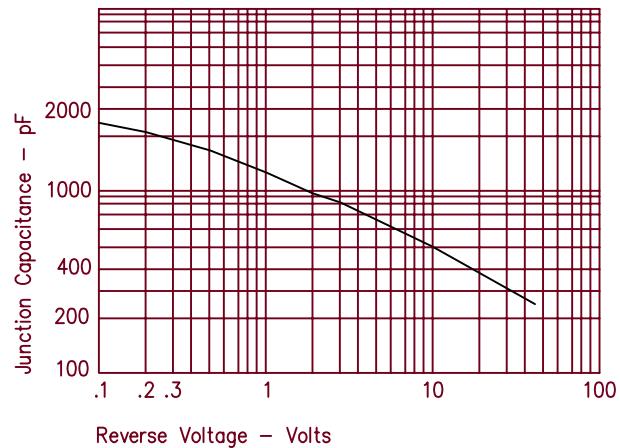


Figure 2
Typical Reverse Characteristics

